

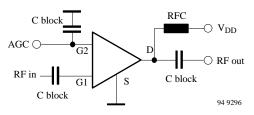
# MOSMIC<sup>®</sup> for TV–Tuner Prestage with 9 V Supply Voltage

MOSMIC - MOS Monolithic Integrated Circuit

#### Applications

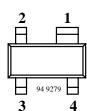
Low noise gain controlled input stages in UHF-and VHF- tuner with 9 V supply voltage.

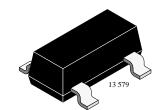
Electrostatic sensitive device. Observe precautions for handling.



#### Features

- Integrated gate protection diodes
- Low noise figure
- 20mS forward transadmittance
- Biasing network on chip



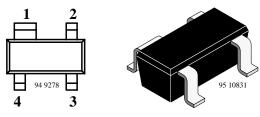


S904T Marking: 904 Plastic case (SOT 143) 1 = Source, 2 = Drain, 3 = Gate 2, 4 = Gate 1

## **Absolute Maximum Ratings**

 $T_{amb} = 25^{\circ}C$ , unless otherwise specified

- Improved cross modulation at gain reduction
- High AGC-range
- SMD package



S904TR Marking: 90R Plastic case (SOT 143R) 1 = Source, 2 = Drain, 3 = Gate 2, 4 = Gate 1

Parameter	Test Conditions	Symbol	Value	Unit
Drain - source voltage		V <sub>DS</sub>	12	V
Drain current		I <sub>D</sub>	30	mA
Gate 1/Gate 2 - source peak current		±I <sub>G1/G2SM</sub>	10	mA
Gate 1/Gate 2 - source voltage		±V <sub>G1/G2SM</sub>		V
Total power dissipation	T <sub>amb</sub> ≤ 60 °C	P <sub>tot</sub>	200	mW
Channel temperature		T <sub>Ch</sub>	150	°C
Storage temperature range		T <sub>stg</sub>	-55 to +150	°C

#### **Maximum Thermal Resistance**

 $T_{amb} = 25^{\circ}C$ , unless otherwise specified

Parameter	Test Conditions	Symbol	Value	Unit
Channel ambient	on glass fibre printed board (25 x 20 x 1.5) mm <sup>3</sup> plated with 35µm Cu	R <sub>thChA</sub>	450	K/W

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#### **Vishay Telefunken**



#### **Electrical DC Characteristics**

 $T_{amb} = 25^{\circ}C$ , unless otherwise specified

Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
Gate 1 - source breakdown voltage	$\pm I_{G1S}$ = 10 mA, $V_{G2S}$ = $V_{DS}$ = 0	±V <sub>(BR)G1SS</sub>	7		10	V
Gate 2 - source breakdown voltage	$\pm I_{G2S}$ = 10 mA, $V_{G1S}$ = $V_{DS}$ = 0	±V <sub>(BR)G2SS</sub>	7		10	V
Gate 1 - source	$+V_{G1S} = 5 V, V_{G2S} = V_{DS} = 0$	+I <sub>G1SS</sub>			50	μA
leakage current	$-V_{G1S} = 5 V, V_{G2S} = V_{DS} = 0$	-I <sub>G1SS</sub>			100	μA
Gate 2 - source leakage current	$\pm V_{G2S} = 5 \text{ V}, V_{G1S} = V_{DS} = 0$	±I <sub>G2SS</sub>			20	nA
Drain current	$V_{DS} = 9 V, V_{G1S} = 0, V_{G2S} = 4 V$	I <sub>DSS</sub>	50		500	μA
Self-biased operating current	$V_{DS} = 9 V, V_{G1S} = nc, V_{G2S} = 4 V$	I <sub>DSP</sub>	7	10	14	mA
Gate 2 - source cut-off voltage	$V_{DS}$ = 9 V, $V_{G1S}$ = nc, $I_D$ = 20 $\mu$ A	V <sub>G2S(OFF)</sub>		1.0		V

#### **Electrical AC Characteristics**

 $V_{DS}$  = 9 V,  $V_{G2S}$  = 4 V, f = 1 MHz ,  $T_{amb}$  = 25  $^{\circ}C,$  unless otherwise specified

Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
Forward transadmittance		y <sub>21s</sub>	17	20	23	mS
Gate 1 input capacitance		C <sub>issg1</sub>		2.0	2.5	рF
Feedback capacitance		C <sub>rss</sub>		20		fF
Output capacitance		Coss		0.9		рF
Power gain	G <sub>S</sub> = 2 mS, G <sub>L</sub> = 0.5 mS, f = 200 MHz	G <sub>ps</sub>		26		dB
	G <sub>S</sub> = 3,3 mS, G <sub>L</sub> = 1 mS, f = 800 MHz	G <sub>ps</sub>	16.5	20		dB
AGC range	$V_{DS} = 9 V$ , $V_{G2S} = 1$ to 4 V, f = 800 MHz	$\Delta G_{ps}$	40			dB
Noise figure	G <sub>S</sub> = 2 mS, G <sub>L</sub> = 0.5 mS, f = 200 MHz	F		1		dB
	G <sub>S</sub> = 3,3 mS, G <sub>L</sub> = 1 mS, f = 800 MHz	F		1.6	2.5	dB

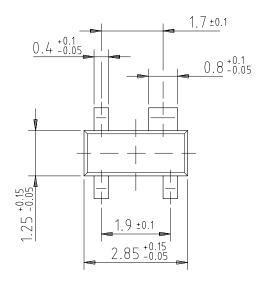
#### Caution for Gate 1 switch-off mode:

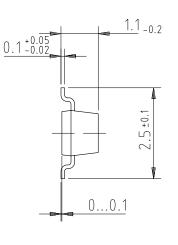
No external DC-voltage on Gate 1 in active mode! Switch-off at Gate 1 with  $V_{G1S} < 0.7$  V is feasible. Using open collector switching transistor (inside of PLL), insert 10 k $\Omega$  collector resistor.



S904T/S904TR Vishay Telefunken

#### Dimensions of S904T in mm

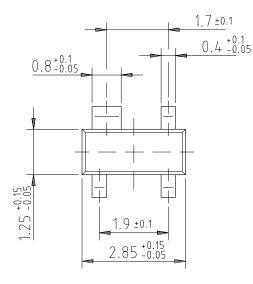


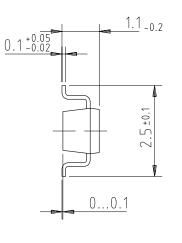






### **Dimensions of S904TR in mm**





96 12239



technical drawings according to DIN specifications

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# S904T/S904TR

#### **Vishay Telefunken**



#### **Ozone Depleting Substances Policy Statement**

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.

2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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